

RT1P436X SERIES

Transistor

Transistor With Resistor

For Switching Application

Silicon PNP Epitaxial Type

DESCRIPTION

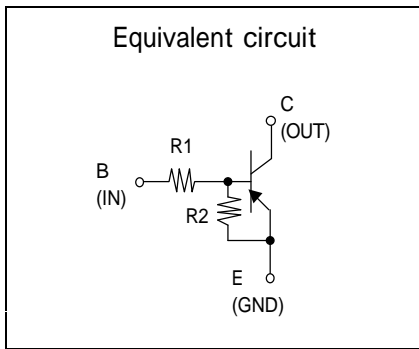
RT1P436X is a one chip transistor with built-in bias resistor, NPN type is RT1N436X.

FEATURE

- Built-in bias resistor (R1=4.7k, R2=47k).

APPLICATION

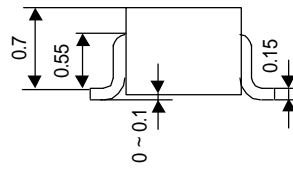
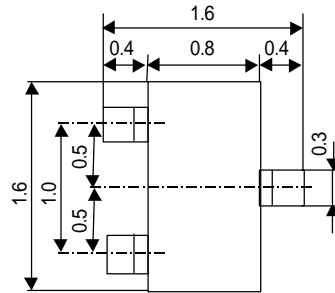
Inverted circuit, switching circuit, interface circuit, driver circuit.



OUTLINE DRAWING

UNIT: mm

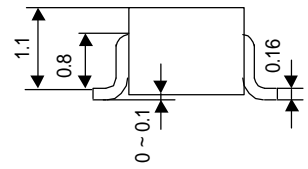
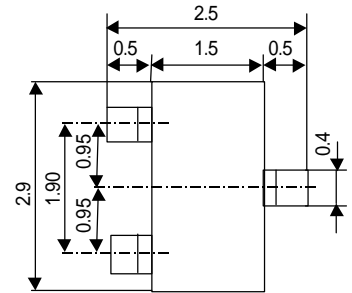
RT1P436U



JEITA: -
JEDEC: -

Terminal Connector
: Base
: Emitter
: Collector

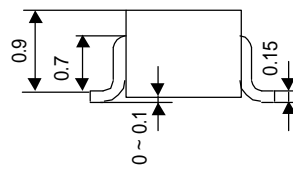
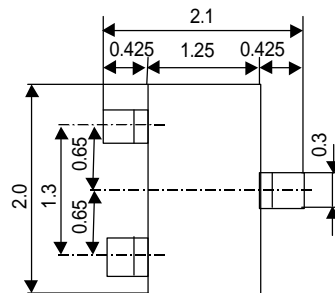
RT1P436C



JEITA: SC-59
JEDEC: Similar to TO-236

Terminal Connector
: Base
: Emitter
: Collector

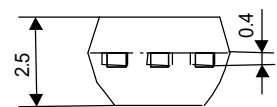
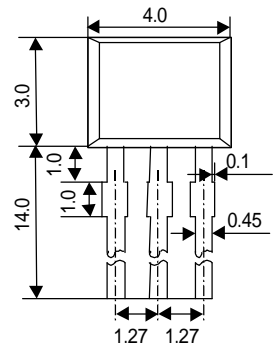
RT1P436M



JEITA: SC-70
JEDEC: -

Terminal Connector
: Base
: Emitter
: Collector

RT1P436S



JEITA: -
JEDEC: -

Terminal Connector
: Emitter
: Collector
: Base

RT1P436X SERIES

Transistor

Transistor With Resistor

For Switching Application

Silicon PNP Epitaxial Type

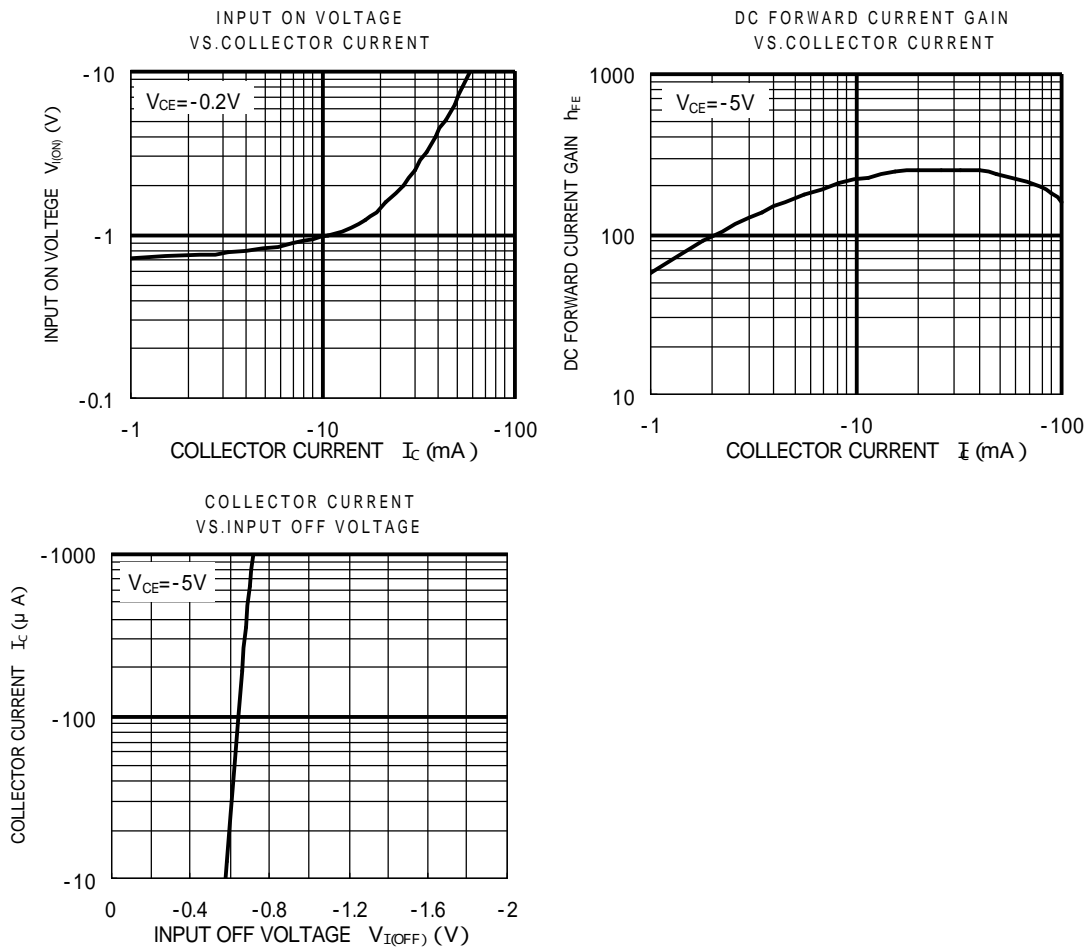
MAXIMUM RATING (Ta=25 °C)

SYMBOL	PARAMETER	RATING				UNIT
		RT1P436U	RT1P436M	RT1P436C	RT1P436S	
V_{CBO}	Collector to Base voltage			-50		V
V_{EBO}	Emitter to Base voltage			-6		V
V_{CEO}	Collector to Emitter voltage			-50		V
I_C	Collector current			-100		mA
I_{CM}	Peak Collector current			-200		mA
P_C	Collector dissipation(Ta=25 °C)	150	200	450		mW
T_j	Junction temperature	+150	+150			
T_{stg}	Storage temperature	-55 ~ +150	-55 ~ +150			

ELECTRICAL CHARACTERISTICS (Ta=25 °C)

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
			MIN	TYP	MAX	
$V_{(BR)CEO}$	C to E break down voltage	$I_C = -100 \mu A, R_{BE} =$	-50			V
I_{CBO}	Collector cut off current	$V_{CB} = -50V, I_E = 0$			-0.1	μA
h_{FE}	DC forward current gain	$V_{CE} = -5V, I_C = -10mA$	80			-
$V_{CE(sat)}$	C to E saturation voltage	$I_C = -10mA, I_B = -0.5mA$		-0.1	-0.3	V
$V_{I(ON)}$	Input on voltage	$V_{CE} = -0.2V, I_C = -5mA$		-0.8	-1.4	V
$V_{I(OFF)}$	Input off voltage	$V_{CE} = -5V, I_C = -100 \mu A$	-0.4	-0.6		V
R_1	Input resistance		3.3	4.7	6.1	k
R_2 / R_1	Resistance ratio		8	10	12	
f_T	Gain band width product	$V_{CE} = -6V, I_E = 10mA$		150		MHz

TYPICAL CHARACTERISTICS





Marketing division, Marketing planning department

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